

Afisarea articolelor 1-1(1) pentru cuvântul-cheie "Wigner function Engineering main heading MOSFET devices"

Quantum transport in a nanosize double-gate metal-oxide-semiconductor field-effect transistor

Croitoru Mihail^{1,2}, Gladilin Vladimir^{1,2}, Fomin Vladimir^{1,2,3}, Devreese Josef T.^{1,3}, Magnus Wim⁴, Schoenmaker Wim J.⁴, Soree Bart⁴

¹ University of Antwerp,

² Moldova State University,

³ Eindhoven University of Technology,

Journal of Applied Physics

/ 2004 / ISSN 0021-8979 /ISSNe 1089-7550

Disponibil online 2 November, 2023. Descarcări-0. Vizualizări-167



Copyright © 2011-2024 Instrumentul Bibliometric Național.

Institutul de Dezvoltare a Societății Informaționale.

Actualizat: 21.06.2024, accesat: 21.06.2024

Disponibil: <https://ibn.idsi.md>

